## NSN 5961-00-008-8257

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Inclosure Material:

Metal

**Overall Length:** 

0.468 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.5

breakdown voltage, emitter-to-base, collector open

**Current Rating Per Characteristic:** 

Between 1.00 amperes source cutoff current and 2.00 amperes source cutoff current

Power Rating Per Characteristic:

30.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

**Special Features:** 

Junction pattern arrangement: pnp

Thread Series Designator:

Unf

**Terminal Type And Quantity:** 

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0